

Article

Supplementary Material High performance of Metallic Thin Films for Resistance Temperature Devices with Antimicrobial Properties

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Abstract: Our purpose with this supplementary material is to show the experimental procedure details, the cross-section SEM micrographs, and the thermoresistive response for the $\text{Ti}_{0.54}\text{Cu}_{0.46}$ and $\text{Ti}_{0.74}\text{Cu}_{0.26}$ thin films.



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1. SEM. micrographs

Figure S1 shows the cross-section SEM. micrographs for $\text{Ti}_{1-x}\text{Cu}_x$ thin films analyzed in this letter. Through cross-section SEM. micrographs, it was possible to determine the thickness of the thin films, 46.6 nm for $\text{Ti}_{0.74}\text{Cu}_{0.26}$, 39.4 nm for $\text{Ti}_{0.70}\text{Cu}_{0.30}$, and 53.9 nm for $\text{Ti}_{0.54}\text{Cu}_{0.46}$.

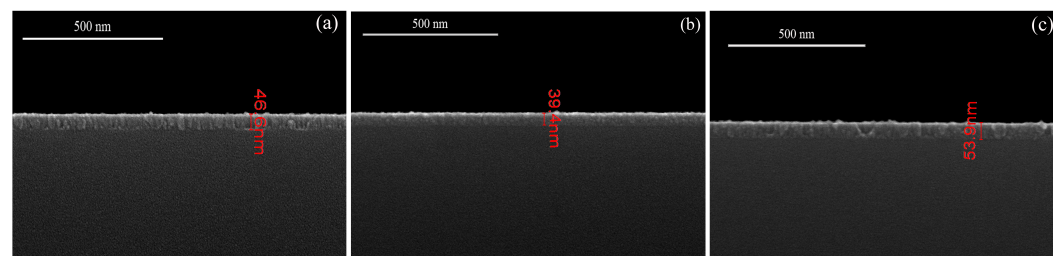


Figure S1. Cross-section S.E.M. micrographs for: (a) $\text{Ti}_{0.74}\text{Cu}_{0.26}$ thin film; (b) $\text{Ti}_{0.70}\text{Cu}_{0.30}$ thin film; (c) $\text{Ti}_{0.54}\text{Cu}_{0.46}$ thin film.

2. Thermosensitive response

Figure S2 shows the electrical resistance variation to the applied temperature to the $\text{Ti}_{0.74}\text{Cu}_{0.26}$ and $\text{Ti}_{0.54}\text{Cu}_{0.46}$ thin films. The $\text{Ti}_{0.74}\text{Cu}_{0.26}$ film presents the largest variation in the electrical resistance, Figure S2a, among the compositions analyzed in this work, and as a consequence, the highest TCR, see Figure S2c. This is due to the lower copper content present in the film. Although the TCR is high, this composition does not show stability in the thermosensitive response, Figure S2b, compared to $\text{Ti}_{0.70}\text{Cu}_{0.30}$ film, during the heating and cooling cycles.

The $\text{Ti}_{0.54}\text{Cu}_{0.46}$ film shows the smallest variation in the electrical resistance, Figure S2c, due to the higher percentage of copper present in the sample, which results in lower TRC in comparison with the $\text{Ti}_{0.70}\text{Cu}_{0.30}$.

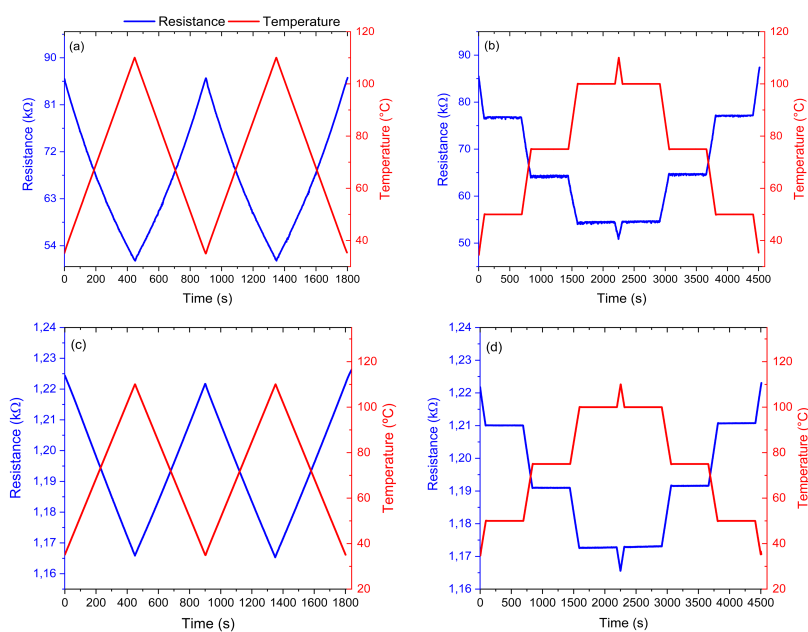


Figure S 2. (a) Electrical resistance measured under temperature cycles for $\text{Ti}_{0.74}\text{Cu}_{0.26}$ sample. (b) Electrical resistance stability for 50, 75, and 100 °C for periods of 10 minutes for $\text{Ti}_{0.74}\text{Cu}_{0.26}$. (c) Similar cycles measurements for $\text{Ti}_{0.54}\text{Cu}_{0.46}$. (d) Similar stability resistance for $\text{Ti}_{0.54}\text{Cu}_{0.46}$ sample.